

Quad Operational Amplifier

GENERAL DESCRIPTION

The XR-4741 is an array of four independent internally-compensated operational amplifiers on a single silicon chip, each similar to the popular 741. Each amplifier offers performance equal to or better than the 741 type in all respects. It has high slew rate, superior bandwidth, and low noise, which makes it excellent for audio amplifiers or active filter applications.

FEATURES

Short-Circuit Protection
 Internal Frequency Compensation
 No Latch-Up
 Wide Common-Mode and Differential Voltage Ranges
 Matched Gain-Bandwidth
 High Slew Rate $1.6\text{V}/\mu\text{S}(\text{Typ})$
 Unity Gain-Bandwidth $3.5\text{ MHz}(\text{Typ})$
 Low Noise Voltage $9\text{ nV}/\sqrt{\text{Hz}}$
 Input Offset Current $60\text{ nA}(\text{Typ})$
 Input Offset Voltage $.5\text{ mV}(\text{Typ})$
 Supply Range $\pm 2\text{V to } \pm 20\text{V}$

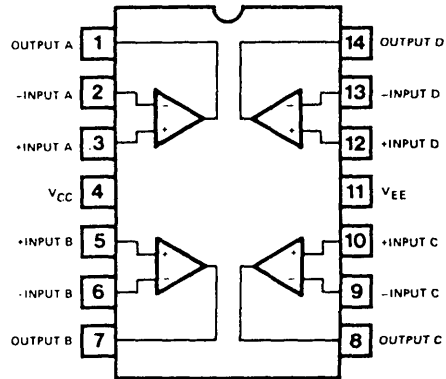
APPLICATIONS

Buffer Amplifiers
 Summing/Differencing Amplifiers
 Instrumentation Amplifiers
 Active Filters
 Signal Processing
 Sample and Differencing
 I to V Converters
 Integrators
 Simulated Components
 Analog Computers

ABSOLUTE MAXIMUM RATINGS

Supply Voltage	
XR-4741	± 20
Common Mode Voltage	V_{EE} to V_{CC}
Output Short-Circuit Duration	Indefinite
Differential Input Voltage	$\pm 30\text{V}$
Internal Power Dissipation	
Ceramic Package:	880 mW
Derate above $T_A = +25^\circ\text{C}$	5.8 mW/ $^\circ\text{C}$
Plastic Package:	625 mW
Derate above $T_A = +25^\circ\text{C}$	5 mW/ $^\circ\text{C}$
Storage Temperature Range:	$-65^\circ\text{C to } +150^\circ\text{C}$

FUNCTIONAL BLOCK DIAGRAM



5

ORDERING INFORMATION

Part Number	Package	Operating Temperature
XR-4741M	Ceramic	$-55^\circ\text{C to } +125^\circ\text{C}$
XR-4741CN	Ceramic	$0^\circ\text{C to } +70^\circ\text{C}$
XR-4741CP	Plastic	$0^\circ\text{C to } +70^\circ\text{C}$

SYSTEM DESCRIPTION

The XR-4741 is a quad independently programmable operational amplifier featuring improved performance over industry standard devices such as the 741. Amplifier bias currents can be "programmed" by a single resistor to Pin 8. Bias currents can range from less than $1\text{ }\mu\text{A}$ to over $75\text{ }\mu\text{A}$, thus affording the designer flexibility along the device speed/power consumption trade off curve.

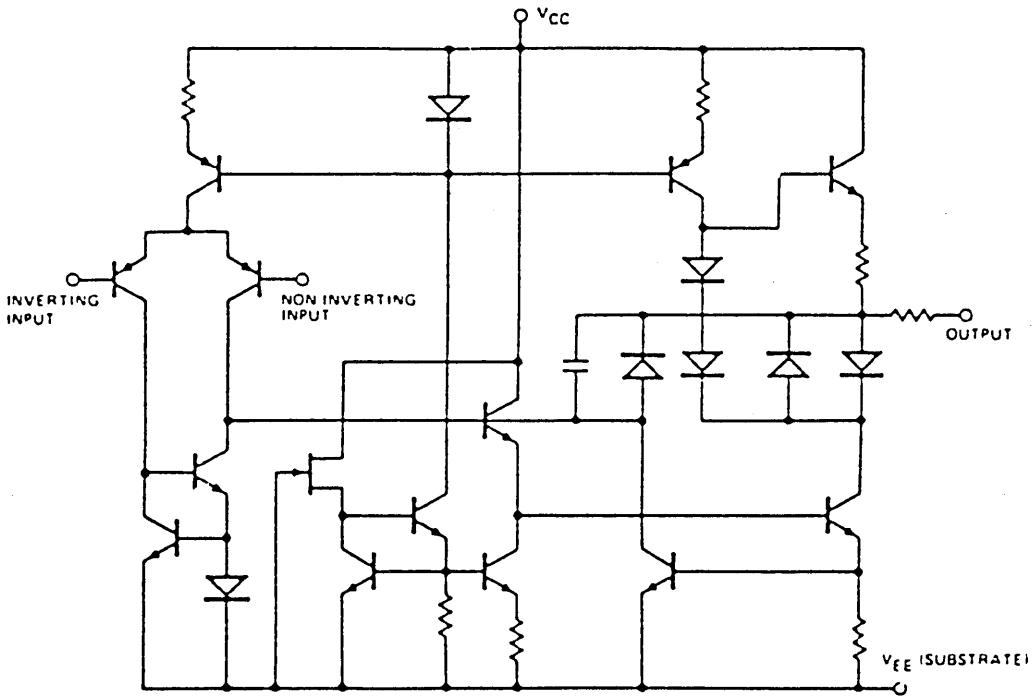
XR-4741

ELECTRICAL CHARACTERISTICS

Test Conditions: $T_A = +25^\circ\text{C}$, $V_S = \pm 15\text{ V}$ unless otherwise specified.

PARAMETERS	XR-4741M			XR-4741C			UNITS	SYMBOLS	CONDITIONS
	MIN	TYP	MAX	MIN	TYP	MAX			
Input Offset Voltage		0.5	3.0		1.0	5.0	mV	$ V_{io} $	$R_S \leq 10\text{ K}\Omega$
Input Offset Current		10	30		10	50	nA	$ I_{io} $	
Input Bias Current		60	200		60	300	nA	$ I_b $	
Differential Input Resistance		5			5		M Ω	R_{in}	
Input Noise Voltage ($f = 1\text{ kHz}$)		9			9		nV/ $\sqrt{\text{Hz}}$		
Large Signal Voltage Gain	50	100		25	50		V/mV	A_{VOL}	$R_L \geq 2\text{ K}\Omega$ $V_{out} = \pm 10\text{ V}$
Output Voltage Swing	± 12 ± 10	± 13.7 ± 12.5		± 12 ± 10	± 13.7 ± 12.5		V V	V_{out} V_{out}	$R_L \geq 10\text{ K}\Omega$ $R_L \geq 2\text{ K}\Omega$
Full Power Bandwidth		25			25		kHz		
Output Resistance		300			300		Ω		
Input Voltage Range	± 12	± 13.5		± 12	± 13.5		V	V_{ICM}	
Common Mode Rejection Ratio	80	100		80	100		dB	CMRR	$R_S \leq 10\text{ K}\Omega$
Supply Voltage Rejection Ratio		10	100		10	100	$\mu\text{V/V}$	PSRR	$R_S \leq 10\text{ K}\Omega$
Power Consumption			150			210	mW	P_i	
Transient Response (unity gain) Risetime Overshoot		.07 20			.07 20		μs %	t_r t_o	$V_{in} = 20\text{ mV}$ $R_L = 2\text{ K}\Omega$ $C_L \leq 100\text{ pF}$
Unit Gain Bandwidth		3.5			3.5		MHz	BW	
Slew Rate (unity gain)		1.6			1.6		V/ μs	dV_{out}/dt	$R_L \geq 2\text{ K}\Omega$
Channel Separation (open loop) (Gain of 100)		120 105			120 105		dB dB		$f = 10\text{ KHz}$ $R_S = 1\text{ K}\Omega$ $f = 10\text{ KHz}$ $R_S = 1\text{ K}\Omega$
The following specifications apply for $-55^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$ for XR-4741M; $0^\circ\text{C} \leq T_A \leq +70^\circ\text{C}$ for XR-4741C									
Input Offset Voltage		4.0	5.0		5.0	6.5	mV	$ V_{io} $	$R_S \leq 10\text{ K}\Omega$
Input Offset Current			75			100	nA	$ I_{io} $	
Input Bias Current			325			400	nA	I_b	
Input Voltage Range	± 12			± 12			V		
Common Mode Rejection Ratio	74			74			db		
Large-Signal Voltage Gain	25			15			V/mV	A_{VOL}	$R_L \geq 2\text{ K}\Omega$ $V_{out} = \pm 10\text{ V}$
Output Voltage Swing	± 10	± 12.5		± 10	± 12.5		V	V_{out}	$R_L = 2\text{ K}\Omega$
Power Consumption	± 12.0	± 13.7		± 12	± 13.7		mW	P_i	$R_L \geq 10\text{ K}\Omega$ $V_S = \pm 15\text{ V}$ $T_A = \text{High}$ $T_A = \text{Low}$
Supply Voltage Rejection Ratio		100	150 200 $\mu\text{V/V}$		100	150 200 $\mu\text{V/V}$	mW	P_i P_i	
Output Short-Circuit Current	± 5	± 15		± 5	± 15		mA	I_{SC}	

XR-4741



1/4 of XR-4741

EQUIVALENT SCHEMATIC DIAGRAM